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Citation for published version (APA): Di Nuzzo, D., Kulkarni, C., Zhao, B., Smolinsky, E., Tassinari, F., Meskers, S. C. J., Naaman, R., Meijer, E. W., & Friend, R. H. (2017). High circular polarization of electroluminescence achieved via self-assembly of a lightemitting chiral conjugated Polymer into multidomain cholesteric films. ACS Nano, 11(12), 12713-12722. https://doi.org/10.1021/acsnano.7b07390

DOI: 10.1021/acsnano.7b07390

Document status and date:

Published: 26/12/2017

Document Version:

Accepted manuscript including changes made at the peer-review stage

Please check the document version of this publication:

• A submitted manuscript is the version of the article upon submission and before peer-review. There can be important differences between the submitted version and the official published version of record. People interested in the research are advised to contact the author for the final version of the publication, or visit the DOI to the publisher's website.

• The final author version and the galley proof are versions of the publication after peer review.

 The final published version features the final layout of the paper including the volume, issue and page numbers.

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High Circular Polarization of Electro-Luminescence Achieved *via* Self-Assembly of a Light-Emitting Chiral Conjugated Polymer into Multi-Domain Cholesteric Films

Daniele Di Nuzzo ^a*, Chidambar Kulkarni ^b, Baodan Zhao ^a, Eilam Smolinksy ^c, Francesco Tassinari ^c, Stefan C.J. Meskers ^b, Ron Naaman ^c, E.W. Meijer ^b, Richard H. Friend ^a

^a Cavendish Laboratory, University of Cambridge, JJ Thomson Avenue, Cambridge, CB3 0HE, United Kingdom.

^b Institute for Complex Molecular Systems, Laboratory of Macromolecular and Organic Chemistry, Eindhoven University of Technology, PO Box 513, Eindhoven, 5600 MB, The Netherlands.

^c Department of Chemical Physics, Weizmann Institute of Science, Rehovot 76100, Israel.

Corresponding author

* Daniele Di Nuzzo (<u>dd467@cam.ac.uk</u>)

Abstract

We demonstrate a facile route to obtain high and broad-band circular polarization of electroluminescence in single layer polymer OLEDs. As light emitting material we use a donoracceptor polyfluorene with enantiomerically pure chiral side-chains. We show that upon thermal annealing the polymer self assembles into a multi-domain cholesteric film. By varying the thickness of the polymer emitting layer, we achieve high levels of circular polarization of electro-luminescence (up to 40% excess of right-handed polarization), which are the highest reported for polymer OLEDs not using chiral dopants or alignment layers. Mueller matrix ellipsometry shows strong optical anisotropies in the film, indicating that the circular polarization of luminescence arises mainly after the photon has been generated, through selective scattering and birefringence correlated in direction to the initial linear polarization of the photon. Our work demonstrates that chirally-substituted conjugated polymers can combine photonic and semiconducting properties for novel functionalities in optoelectronic devices.

TOC GRAPHICS



KEYWORDS: OLEDs; circularly polarized luminescence; light-emitting polymers; chirality; self-assembly

Sources of circularly polarized light are interesting for a range of new applications across different fields such as spin-optoelectronics,^{1,2} optical manipulation of information,^{3,4} 3D imaging systems, biology and medicine.⁵⁻⁷ Organic LEDs can emit Circularly Polarized Electro-Luminescence (CPEL) when the emitting organic material is chiral and of one handedness only. This makes them excellent candidates as sources of circularly polarized light, due to the ease of fabrication, possible large area processing, low cost and freedom to tune the optoelectronic properties of the organic semiconductor *via* molecular design.

Moreover, CPEL is highly desirable to enhance the efficiency of OLED-based displays: to enhance the contrast of OLED-based commercial displays, circularly polarizing filters are applied that trap ambient light in the display. This implies that, because it is randomly polarized, only half of the Electro-Luminescence (EL) can exit the display. Attaining full circular polarization of EL could therefore double the efficiency of OLED-based displays.

In recent years, considerable efforts have been made to achieve strong CPEL in OLEDs. However, besides two recent examples^{8,9} low levels of polarization are commonly achieved, below 10-15% excess of one handedness (**Table S1**, Supporting Information). Several types of materials for the emitting layer have been used: lanthanides complexes,⁹ phosphorescent organic complexes¹⁰⁻¹² and conjugated polymers.^{8, 13-16} It is useful to point out that two main distinct mechanisms can generate Circularly Polarized Luminescence (CPL) in molecular materials. First, CPL can originate *locally*, *i.e.* at the molecular site of light emission. In this case, for the emitted light to be fully circularly polarized, the optical transition has to be magnetic-dipole allowed and electric-dipole forbidden.¹⁷ This requirement poses a challenge for reaching strong circular polarization whilst maintaining high luminescence efficiency. To date, the only known example of chiral molecules with high luminescence efficiency and high circular polarization are chiral lanthanide complexes.¹⁸ The second mechanism that can be exploited to obtain CPL is *non-local*: this is the case of luminescent cholesteric liquid crystals, for which, in the limit of thick films (10² nm), circular polarization is largely determined by the anisotropy of the cholesteric dielectric medium and is weakly dependent on the polarization state of light at the site of emission. Strong CPL in polymer films¹⁹ and CPEL in polymer OLEDs^{8,15} were achieved by exploiting this mechanism: in these works alignment layers were used to induce the formation of large cholesteric domains. In some recent cases, chirality was obtained by mixing achiral polymers with chiral dopants.^{8,16}

In this paper we exploit the *non-local* effect of cholesteric order to achieve high levels of CPEL in OLEDs based on a chirally-substituted polyfluorene copolymer with 100% enantiomeric purity acting as emitting layer, without using any chiral dopant and alignment layers. By varying the thickness of the emitting layer, we achieve CPEL with up to 40% excess of right-handed polarization, the second highest value for polymer OLEDs and the highest obtained without the use of chiral dopants or alignment layers. Our polymer consists of a fluorene-benzothiadiazole donor-acceptor repeat unit forming the conjugated backbone, with chiral centres attached to the fluorene moiety to provide enhanced solubility and chiral ordering with preferred handedness in the assembled state. Consistent with previous studies, we observe that self-assembly on the mesoscale occurs when the polymer films are thermally annealed into the liquid crystal phase, giving rise to cholesteric order.^{20,21} Furthermore we find that the annealed films have multi-domain cholesteric liquid crystalline order, with domains in the order of a few hundreds of nanometres in size. We interpret the observed CPEL as arising from circular selective scattering and birefringence in such multi-domain films. Our results show that OLEDs based on multi-domain cholesteric emitting layers allow strong and broad-band CPEL.

Results and discussion

In Fig. 1 the chemical structure of chiral and enantiomerically pure poly(fluorene-altbenzothiadiazole) (c-PFBT) is shown. c-PFBT is used as emitting layer in the OLEDs presented in this work. A standard OLED structure was used: the layers and their respective energy levels are shown in Fig. 1. Hole injection is achieved via a layer of PEDOT:PSS:PFI deposited on top of ITO. PFI (Perfluorinated Ionomer, see Experimental Section for details) was added to increase the work function of PEDOT:PSS and reduce the energy barrier for hole injection into c-PFBT.²² OLEDs with different thicknesses of the c-PFBT emitting layer were fabricated; the thickness of the emitting layer was varied by varying the concentration of c-PFBT in the solution for spin coating, while fixed thicknesses were used for all the other layers. After spin-coating c-PFBT, the samples were annealed at 240°C for 15 minutes in nitrogen atmosphere. An evaporated top contact consisting of Calcium (20 nm) and Silver (80 nm) was used for electron injection. A thin poly2,7-9,9-di-*n*-octylfluorene-*alt*-1,4-phenylene-4-*sec*-butylphenyl layer of imino-1,4phenylene (TFB) was deposited between PEDOT:PSS:PFI and c-PFBT to act as electronblocker.²³



Figure 1. a) Chemical structure of c-PFBT. b) Layers comprising the OLED stack and their energy levels.

The dissymmetry factor g_{EL} in the electro-luminescence of OLEDs comprising a c-PFBT layer of 100, 200 and 400 nm thickness, operated in continuous voltage bias at 10, 15 and 25 V, respectively, is shown in **Fig. 2a**. This corresponded to current densities of 340, 565 and 13 mA/cm² and luminances of 900, 2950 and 80 cd/m², respectively. The Current-Luminance-Voltage characterization of the OLEDs is shown in **Fig. S1**. We define here the EL dissymmetry factor g_{EL} as:

$$g_{\rm EL} = 2 \cdot [EL_{\rm L} - EL_{\rm R}] / [EL_{\rm L} + EL_{\rm R}] \tag{1}$$

where EL_L and EL_R are the EL intensities with left-handed and right-handed circular polarization, respectively. The setup used to measure EL_L and EL_R is described in the experimental section. We measured an excess of right-handed circularly polarization in the EL of all the OLEDs, giving negative values of g_{EL} according to the definition above. By increasing the thickness of the c-PFBT emitting layer, g_{EL} changes dramatically: with a c-PFBT layer thickness of 100 nm we observe that g_{EL} reaches a minimum value of -0.08 at 500 nm. Increasing the thickness of the c-PFBT layer to 200 nm, g_{EL} reaches -0.33 at 500 nm. We note that this is in line with the values of g_{EL} reported for most circularly polarized OLEDs to date (**Supporting Table S1**). When we further increase the thickness of the c-PFBT layer to 400 nm, we obtain a minimum g_{EL} of -0.6, with the peak wavelength shifting to 520 nm. Not only the minimum value, but also the dependence of g_{EL} on wavelength varies with the thickness of the c-PFBT layer: with the 400 nm thick OLED a band centred at 700-750 nm appears, as opposed to the thinner devices, where g_{EL} decreases monotonically with wavelength.

We have also measured CPEL under pulsed-voltage operation of the OLEDs: **Fig. 2a** shows g_{EL} measured on the 400 nm thick OLED when applying square voltage pulses (going from 0 V to 35 V) with a duration of 1 µs, at a repetition rate of 1kHz; we observe that CPEL is higher than in the continuous bias case, with g_{EL} reaching -0.8 at 510 nm (*i.e.* corresponding to 40% excess of right-handed polarization). We found that g_{EL} decreases when the duration of the pulses is increased, reaching a less negative value of -0.65 at 525 nm under DC bias; furthermore, the peak of g_{EL} shifts to longer wavelengths for the longest pulses (250 µs) reaching 525 nm for the constant voltage case (**Fig. S2**, Supporting Information). The total, unpolarised, EL of the same OLEDs is shown in **Fig. 2b**. We observe a red-shift of EL when going from 100 and 200 nm c-PFBT layers to 400 nm, with the peak of EL shifting from 535 nm to 545 nm. We interpret the changes in EL spectrum as originating from different out-coupling of light when the c-PFBT layer thickness is varied.



Figure 2. a) Dissymmetry factor of electro-luminescence g_{EL} of OLEDs comprising a c-PFBT emitting layer of varying thickness (see legend). g_{EL} was measured at constant voltage bias ("DC", solid lines). g_{EL} measured under 1µs, 35 V pulsed-voltage excitation (1kHz repetition rate) on the 400 nm thick OLED is also shown (circles). b) Corresponding total, unpolarized EL spectra under constant voltage bias.

All the CPEL results presented above were obtained on OLEDs in which the c-PFBT layer had been thermally annealed at 240°C before evaporating the top contact. No CPEL was detected on as-cast OLEDs. The dependence on annealing temperature and thickness of the chiroptical properties of films of chirally substituted polyfluorenes is known: it was previously shown that c-PFBT enters the cholesteric liquid crystalline phase when heated above 150°C.²⁰ Furthermore, it was shown on chiral polyfluorenes that the circular polarization dissymmetry of light transmitted through annealed films is strongly dependent on film thickness, owing to the long range, *non-local* effect of the cholesteric dielectric on light polarization.²¹ Consistently with these previous studies, we observe a 25-fold increase in *apparent* circular dichroism upon

thermal annealing of thin films of c-PFBT (**Fig. 3a**). The internal structural organization of the film leads to unusual optical characteristics and we need therefore to take great care in the definition of the experimental quantities under investigation. In **Fig. 3a** we show the difference in extinction $E = -\log_{10}(T)$ between transmission (*T*) of incident light having left and right circular polarization, and using unpolarised (*U*) detection. The resulting quantity $E_{\rm L}^{\rm U} - E_{\rm R}^{\rm U}$ can be regarded as an apparent circular dichroism where we note that in principle both absorption and scattering can contribute to extinction. In the wavelength region above 500 nm, where the polymer does not show allowed optical absorption, the circular differential extinction is mainly due to circular selective scattering of light.

Fig. 3b and c show AFM microscopy images of as cast and annealed 400 nm thick films deposited on fused silica substrates, respectively. As-cast films show spherical morphology (**Fig. 3b**), whereas upon annealing the morphology changes to an inter-connected network of fibres (**Fig. 3c**). The fibres are typically ca. 200-300 nm wide. Polarized Optical Microscopy (POM) with c-PFBT films between two crossed polarizers shows no birefringence for as cast films (**Fig. 3d**). In contrast, the annealed films do show birefringence, without any preferred orientation (**Fig. 3e**). The image of the annealed film suggests small birefringent domains with dimensions in the order of 1 micrometre. The strong dissymmetry in extinction and the presence of non-oriented birefringence in POM indicate that upon thermal annealing multi-domain cholesteric films are produced, containing cholesteric domains oriented at different angles between each other. Note that we could not observe macroscopic circular selective reflection on the films; this observation confirms the disordered nature of the films.²⁴



Figure 3. a) Difference in extinction *E* for left and right circularly polarized incident light and unpolarized detection, for films of c-PFBT with thickness around 100 nm, before and after annealing at different temperatures (see legend). b,c) Tapping-mode AFM height images of as cast and annealed films respectively. d,e) Polarized optical microscopy (POM) images of as cast and annealed films respectively when viewed under cross-polarizer. All the films were deposited on fused silica substrates. The thermal annealing of films for AFM and POM was performed at 240 °C for 15 minutes.

The high degree of circular polarization in electro-luminescence (**Fig. 2**) and its relation to the molecular organization induced by thermal annealing (**Fig. 3**) are intriguing and will now be discussed in more detail. In **Fig. 4a** we show the chiroptical properties of an annealed film of c-PFBT spin coated with the same thickness as used in the electro-luminescence measurements (400 nm). We find very high values for the dissymmetry ratio in extinction defined as $g_{EXT} = 2 \cdot [E_L^{U} - E_R^{U}]/[E_L^{U} + E_R^{U}]$. Near the onset of the absorption we find $g_{EXT} = -0.8$. The dissymmetry ratio for photo-luminescence $g_{PL} = 2 \cdot [I_L - I_R]/[I_L + I_R]$, with I_L and I_R the intensity of left and right circularly polarized luminescence for the same 400 nm thick film, also reaches high values near the onset of the luminescence: $g_{PL} = -0.6$. The photo-luminescence has been measured using unpolarised excitation light with 356 nm wavelength and with direction normal to the film and in line with the direction of luminescence bands is consistent with the expected time reversal symmetry for photon absorption and emission near the origin of the bands. The high values for g_{EL} , g_{EXT} and g_{PL} are all consistent with a *non-local* origin of the circular polarization related to a cholesteric organization within the film.

The next issue we address is how the peculiar multi-domain cholesteric organization in the films under study can lead to such high degrees of polarization in photo- and electroluminescence. The hypothesis we investigate is that the light produced by electro-luminescence acquires its polarization characteristics while it travels through the film in the outward direction, *after* the corresponding photon has been generated. In order to test this hypothesis we investigated the transmission of light in the wavelength range corresponding to the emission. In a first naïve approach, we assume that initially the emission is unpolarised and that the relative circular differential transmission of the left and right circular components of the emission lead to net circular polarization. In **Fig. 4b** we illustrate the dissymmetry ratio $g_{\text{TRANS}} = 2 \cdot [T_{\text{L}}^{\text{U}} - T_{\text{R}}^{\text{U}}]/[T_{\text{L}}^{\text{U}} + T_{\text{R}}^{\text{U}}]$ for transmission of left and right circularly polarized incident light and unpolarised detection, for thermally annealed films of c-PFBT with different thicknesses. For the thickest film (400 nm), a broad band in the g_{TRANS} spectrum appears for wavelengths near 1100 nm (see inset in **Fig. 4b**). Because the polymer has no absorption band in this region and does not show any detectable circular selective reflection of light, we assign the negative g_{TRANS} to preferential scattering of left circularly polarized light. The sign and wavelength are consistent with a left-handed cholesteric organization with pitch length around 600 nm and refractive index near 1.7. In the wavelength range 490-700 nm relevant for the emission, the degree of polarization is on the order of 10^{-2} (preferred right-handed transmission). These results show that selective scattering can at least partially contribute to the circular polarization of EL observed in the OLEDs.

A second *non-local* effect that can impact the CPEL in our OLEDs is birefringence. Using a rubbed polyimide alignment layer as substrate for thin thermally annealed films of c-PFBT, we found that the absorption of light involving the allowed transition to the lowest singlet excited state (S₁) is highly linearly polarized parallel to the rubbing direction of the alignment layer. This is consistent with the orientation of the transition dipole moment of the S₁ \leftarrow S₀ transition parallel to the direction of the backbone of the polymer. The luminescence involving the reverse S₁ \rightarrow S₀ transition is therefore expected to be initially polarized in a direction parallel to the polymer chain. However the strong birefringence of the annealed polymer films may change the polarization of this initially linearly polarized light. Because of the cholesteric arrangement of the polymer chains one expects some birefringence in a direction making an angle of 45° with the direction of the polymer chains involved in generation the luminescence. This particular birefringence will convert linearly polarized light into circularly polarized light and contribute to the overall circular polarization of the luminescence. In order to test this scenario experimentally we have performed generalized ellipsometry on polymer films

aligned on polyimide, focussing on the elements of the Mueller matrix involving interconversion of linear and circular polarization. Results are illustrated in Fig. 4c, where we show the degree of circular polarization of light transmitted through aligned and thermally annealed films of c-PFBT of various thickness, under the condition that, on the surface of the film placed at the side of the sample where the light enters, light is linearly polarized in a direction parallel to the polymer chains. Translated to the scenario of luminescence, the resulting quantity $g_{\text{TRANS}^{\parallel}} = 2 \cdot [T_{\parallel}^{\text{L}}]^{\text{L}}$ $T_{\parallel}^{R}/[T_{\parallel}^{L} + T_{\parallel}^{R}]$ would correspond to the circular polarization of light being initially linearly polarized in the direction of the polymer chains at the site of light generation and having travelled through a layer of polymer of the same thickness as in the transmission measurements discussed here. We find that $g_{\text{TRANS}}^{\parallel}$ is quite small for thin films and shows the expected oscillatory pattern as function of film thickness: for films of 180 nm thickness we find a local maximum in the polarization with $g_{\text{TRANS}^{\parallel}}$ as high as -1.2 for wavelengths near 500 nm. For ascast films $g_{\text{TRANS}^{\parallel}}$ was found to be vanishingly small. The high degree of polarization in the aligned and annealed films is consisted with the transmitted light having passed through mainly a single domain within the film. Only under this condition will there be a fixed relation between the sign and direction of the birefringence and the initial linear polarization, leading to a net circular polarization. If domains in the film would be much smaller such that the transmitted light would visit several domains on its path through the film, then the induced net circular polarization is expected to cancel out. We do not have a direct measurement of how many domains light crosses in the non-aligned annealed films that we used in our OLEDs. In principle birefringence could still have a non-negligible effect on the polarization of light generated in non-aligned films. We conclude that both circular selective scattering and birefringence could contribute to the strong CPEL that we observe in OLEDs. A quantitative assessment of the

contribution of the two mechanisms is beyond the scope of the present work.



Figure 4. a) Dissymmetry ratio $g_{EXT} = 2(E_L^U - E_R^U)/(E_L^U + E_R^U)$ for extinction of left and right circularly polarized incident light and unpolarized detection on a 400 nm thick, thermally annealed film of c-PFBT on fused silica. In red, the dissymmetry ratio for photo-luminescence $g_{PL} = 2[I_L - I_R]/[I_L + I_R]$ for the same film is shown. Photo-luminescence intensity *I* was recorded upon excitation with unpolarized light of 356 nm entering the film under normal incidence and propagating in the same direction as used for the emission detection. b) Dissymmetry ratio $g_{TRANS} = 2(T_L^U - T_R^U)/(T_L^U + T_R^U)$ for thermally annealed, non-aligned films of c-PFBT with different thicknesses. The inset shows the circular selective scattering band for the 400 nm thick film in the near infrared spectral range. c) Dissymmetry ratio $g_{TRANS}^{\parallel} = 2(T_{\parallel}^L - T_{\parallel}^R)/(T_{\parallel}^{\perp} + T_{\parallel}^R)$ for aligned films of c-PFBT of different thicknesses, with $T_{\parallel}^L (T_{\parallel}^R)$ denoting the transmission of light that is linearly polarized in the direction parallel to the polymer chains upon entering the film and that leaves the film with left- (right-) handed circular polarization.

To further investigate the impact on CPEL of the disorder present in our multi-domain emitting layers, we have used a model that was developed by Dmitrienko and Belyakov for transmission of light through an imperfect cholesteric liquid crystal.²⁵ Here we used their model to study the effect of the distribution in size and orientation of the cholesteric domains on the circular polarization of EL coming out of the OLED in the normal direction with respect to the substrate. The model considers selective reflection events at individual domains; light waves reflected from or transmitted through different domains are considered to superimpose incoherently, that is with random phases. For the film as a whole, the multiple incoherent reflections amount to *scattering* of light. Reflection at an individual domain of light with the same handedness as that of the cholesteric is described by:

$$r(\alpha) = B \frac{1 - \cos(\alpha kh)}{\alpha^2 kh}$$
(2)

where

$$B = \frac{\delta^2}{8sin^2\theta} \tag{3}$$

and

$$\alpha(k) = \frac{\left(\frac{2\pi}{p}\right) - 2ksin\theta}{k} \tag{4}$$

In Equation (3), δ is defined as $\delta = (\varepsilon_1 - \varepsilon_2)/(\varepsilon_1 + \varepsilon_2)$, where ε_1 and ε_2 are the components of the complex dielectric tensor in the plane normal to the axis of the cholesteric helix. In Equation (4) p is the pitch of the cholesteric and k the wave-vector of light in the dielectric, defined by $k = \left(\frac{2\pi}{\lambda}\right)\bar{\varepsilon}^{1/2}$, where λ is the wavelength of light in the vacuum and $\bar{\varepsilon}$ is the average dielectric function. In Equation (2) h is the thickness of the cholesteric domain, while in Equation (3) θ is the angle at which light impinges on the domain. The polarization of light emerging out of the OLED depends also on the total thickness T of the film from the site of emission to the interface

with the transparent electrode. *T*, *h* and θ are schematically represented in **Fig. 5a**. The components ε_1 and ε_2 of the dielectric tensor were measured by ellipsometry on a thin film (23 nm) on quartz. The dependence of δ^2 on wavelength obtained from the measured components of the dielectric tensor is shown in **Fig. S3**. As mentioned above, the cholesteric pitch in our films was measured to be 600 nm.

B is almost constant at long wavelengths away from resonance, while it increases sharply approaching the onset of light absorption, due to the increase in δ^2 (**Fig. S3**). The range of wavelengths close to the onset of absorption is particularly relevant in our case, since it is where the peak of electro-luminescence occurs. The term $\frac{1-\cos(\alpha kh)}{\alpha^2 kh}$ in Equation (2) takes into account the Bragg-type circular selective reflection of light on a single cholesteric domain.

Following the formalism of ref. 25 we calculate the dissymmetry factor g_{EL} of the EL emitted along the direction normal to the substrate (**Fig. 5a**) using Equation (1) and the following expression for EL_L and EL_R:

$$EL_L = \frac{m}{(\mu + \mu_d)\sinh(mT) + m\cosh(mT)}$$
(5)

$$EL_R = e^{-\mu T} \tag{6}$$

where $m = (\mu^2 + 2\mu\mu_d)^{1/2}$, μ is the linear absorption coefficient, and $\mu_d = 4kr$, with *r* defined in Equation (2) and *k* the wave-vector of light in the dielectric.

We consider the limiting case in which light-emission occurs with linear polarization and close to the cathode, with light traversing the whole emitting layer before being emitted. Fig. 5b shows the calculated absolute dissymmetry factor g_{EL} as function of wavelength and film thickness, using $\theta = 90^{\circ}$. The simulated dependence of g_{EL} on film thickness is in agreement with

the experiment (**Fig. 2**). The spectral dependence is also well reproduced, with the calculated g_{EL} peaking at 500 nm and decreasing monotonically with increasing wavelength, as observed in the experiments on the thinner (100 and 200 nm) OLEDs. We also note that modelling successfully reproduces the red-shift of the peak of g_{EL} that was observed in OLEDs with increasing layer thickness (**Fig. 2a**).

In Fig. 5b, g_{EL} for the thickest film (400 nm) is calculated using 200 nm for the thickness of the cholesteric crystals; we show in Fig. 5c that when the cholesteric crystal thickness is increased the spectrum changes drastically, with a broad band arising and shifting to long wavelengths, peaking at 880 nm in the case of h = 400 nm (*i.e.* the total thickness of the film). The new band in the simulations is a consequence of the circular selective reflection of light at the individual domains (term $\frac{1-\cos(\alpha kh)}{\alpha^2 kh}$ in Equation 2). Based on the results in Fig. 5c, we conclude that the band peaked at 700-750 nm observed in the 400 nm thick OLED (Fig. 2a) indicates the existence of cholesteric domains with a range of thicknesses up to the full thickness of the emitting layer. This is also consistent with the results presented in Fig. 4b. The calculated values of g_{EL} are one order of magnitude smaller than the experimental ones. However, when the angle of incidence of light on the single cholesteric crystals is increased, we obtain much larger values, closer to the range of the experimental values (Fig. 5d). Large angles of incidence are realistic, considering the orientational disorder observed in AFM (Fig. 3d).

Note that here we have shown the effect of individual parameters (θ, h, T) on the calculated g_{EL} : we expect the measured polarization to depend on an average over these parameters, which would take into account the profile of the recombination-zone (average over a distribution of values of *T*), the distribution of angles of incidence (θ) and the distribution of thicknesses of the cholesteric domains inside the film (*h*). For example, averaging over a

distribution of cholesteric domain thicknesses h would result in a broad spectrum of g_{EL} , as can be appreciated from **Fig. 5c**, and would explain the broad g_{EL} spectrum observed experimentally in the 400 nm thick OLED (**Fig. 2a**). We do not have a direct measurement of the exact distribution of domain size and orientation in the films, which would be necessary for a more quantitative treatment. Furthermore, here we have not included wave-guiding of EL in the emitting layer and reflection at the back metal electrode, which could also impact the spectral shape and intensity of CPEL.



Figure 5. a) Schematic representation of the polycrystalline cholesteric film in the OLED stack (thicknesses are not in scale). Some of the parameters used in the model are shown; the cholesteric domains are represented by groups of black lines, with z the direction of the cholesteric helical axis. The direction of detection of electro-luminescence (EL) with respect to the substrate is also show. b) Calculated g_{EL} for different values of T and h. Panels c) and d) show the effect of varying h and θ respectively, on the calculated g_{EL} for T = 400 nm and h = 200 nm. All calculations were performed using a cholesteric pitch of 600 nm.

In **Fig. 2a** we have shown that g_{EL} goes from -0.6 to -0.8 when passing from 25 V constant voltage bias to 35 V pulsed bias (1 µs). We interpret the increase in polarization as related to the variation of the recombination with bias: due to the asymmetry between hole (barrier limited) and electron (ohmic) injection into the emitting layer, the recombination zone is expected to be close to the transparent electrode; when the voltage is increased, the recombination zone extends deeper in the emitting layer, with the results that EL traverses more dielectric and the polarization increases. We found that the strongest polarization is achieved

with short bias pulses, while g_{EL} reduces when the length of the pulses at 35 V is increased (Fig. S2): this effect is possibly due to local heating affecting the dielectric function of the emitting layer. Heating is expected to be non-negligible at the high voltages applied on thick layers and is likely to be stronger when using long pulses or constant voltage. Our results suggest that the standard OLED structure used in this work limits the highest g_{EL} that is possible to obtain for a given thickness of the emitting layer, due to the unfavourable position of the recombination zone close to the transparent anode. Tuning the OLED structure in order to have the recombination zone farther from the transparent contact will allow high $g_{\rm EL}$ at lower driving voltages. The position of the recombination zone could be varied for example by choice of transport layers. In general, the rather large thickness of the cholesteric emitting layer required by our non-local approach to strong CPEL presents a challenge to achieving high performance devices: to reach substantial charge injection and light emission, high driving voltages are required in the thick structures. This in turn hinders power efficiency, as can be seen in Fig. S1. This limitation could be overcome by improving charge injection; Kabra et al. have previously demonstrated that ohmic hole injection in inverted-structure polymer LEDs allows to use thick emitting layers while maintaining high power efficiency.²⁶ We believe that if efficient charge injection is obtained in concert with optimal position of the recombination zone far from the transparent anode, strong CPEL and high power efficiency can be achieved simultaneously.

It is also worth recalling here the results by Zinna et al. in OLEDs based on chiral lanthanide complexes, where EL is strongly polarized at the site of emission (*i.e. locally*)⁹: in their study it was found that to maximize g_{EL} the recombination zone has to be positioned as close as possible to the transparent anode, to minimize the contribution of light which has switched to opposite polarization handedness after reflection at the metallic back electrode. It is

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therefore interesting to note how different mechanisms of CPEL generation translate into different requirements for the position of the recombination zone.

Finally, we show on a 100 nm thick c-PFBT OLEDs that circular polarization can be switched ON and OFF when short, high-voltage pulses are applied. The short pulses allow us to use a large range of applied voltages without damaging the OLEDs. **Fig. 6** shows g_{EL} in two different cases: 6V, 10 µs-long square pulses and 20V, 5 µs-long square pulses. The repetition rate was 1 kHz in both cases. We observe that no polarization is present when 6V pulses are applied, while $g_{EL} = -0.15$ at 500 nm is achieved with 20 V pulses. Similarly to the case of the 400 nm thick layer described above, we interpret this observation in terms of the recombination zone depth in the emitting layer: at 6V and with a 10 µs pulses the recombination zone is expected to be narrow and close to the transparent electrode; under these conditions the actual dielectric thickness that EL travels across is close to zero and virtually no polarization can occur. At 20 V, instead, there is enough electric field across the c-PFBT layer to extend the recombination zone deeper, towards the back electrode. Hence a relatively large value of g_{EL} is achieved, ca. 2-fold higher (at 500 nm) than the one recorded when using a 10 V constant bias (**Fig. 2a**).



Figure 6. Dissymmetry factor of electro-luminescence g_{EL} of an OLEDs comprising a 100 nm c-PFBT, measured under pulsed-voltage excitation at 6 V, 10 μ s (red symbols) and 20 V, 5 μ s (black symbols). A repetition rate of 1kHz was used in both cases.

Conclusions

In conclusion, in this work we have shown very strong circular polarization of electroluminescence from single-layer, solution processed polymer OLEDs based on a chiral enantiomerically pure polyfluorene copolymer as emitting material; when using a thermally annealed and thick (400 nm) polymer emitting layer we recorded up to 40% excess of righthanded circular polarization under pulsed voltage bias operation ($g_{EL} = -0.8$) and 30% ($g_{EL} =$ -0.6) under constant voltage bias. These are between the highest values of CPEL reported for OLEDs and the highest achieved without the use of chiral dopants or alignment layers. We also showed that CPEL can be controlled electrically by varying the OLED operation mode, adding a further functionality to these devices.

We find that thermal annealing produces cholesteric films with domains having

orientational and size disorder throughout the sample. The disordered, multi-domain cholesteric films show no appreciable circular selective reflection. Yet domains are large enough to give rise to circular selective scattering and linear birefringence that is correlated in direction to the initial linear polarization of the luminescence photon. Experimental determination of the Mueller matrix of the films show efficient conversion of linearly polarized light into circularly polarized radiation. We conclude that the high levels of CPEL measured in our devices arise mainly *after* the photon has been generated during the passage of the photon through the film in the outward direction. The genesis of circular polarization involves selective scattering and birefringence.

We believe that the approach to CPEL based on *non-local* effects (circular selective scattering and birefringence) in multi-domain cholesterics is very promising because of the ease of fabrication, only requiring thermal annealing. Another crucial advantage is that at wavelengths close to resonance, where most electro-luminescence from the polymer occurs, high polarization can be achieved due to the strong dielectric anisotropy: this might not always be possible in a mono-domain cholesteric film, depending on the pitch length and the resulting Bragg reflection conditions. Furthermore, we show that CPEL in our devices is broad-band, another aspect that is generally difficult to obtain if relying only on Bragg reflection in a perfect, mono-domain cholesteric. Finally, we note that because the cholesteric domains are scattering centres, a beneficial impact on the out-coupling of EL in the direction normal to the OLED substrate might be expected.

Our work demonstrates a facile and generally applicable fabrication route to obtain OLEDs with high levels of circular polarization; we foresee that 100 % polarized broad-band CPEL can be achieved in OLEDs with thick (a few hundreds of nanometres) multi-domain cholesteric emitting layers: this will involve tuning charge mobility and injection, in order for the

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recombination zone to be located far from the transparent contact, already at low driving voltage. More generally, we demonstrate that chirally-substituted conjugated polymers can combine semiconducting and photonic functionalities: this makes them an interesting class of materials for advanced manipulation of light in optoelectronic devices.

Methods

Synthesis of c-PFBT: c-PFBT was synthesized¹⁹ and further purified to remove palladium catalyst according to reported procedures.^{27, 28}

2,7-bis(pinacoyl)-9,9-bis((S)-3,7-dimethyloctyl)fluorene boronic ester (616 mg, 0.88 mmol, 1.0 eq.), 4,7-dibromobenzothiadiazole (259 mg, 0.88 mmol, 1.0 eq.) and oven dried (140 °C) sodium carbonate (981 mg, 9.25 mmol, 10.5 eq.) were taken in a 3-necked round bottom flask (100 mL) fitted with a reflux condenser and an argon inlet. The flask was evacuated and back-filled with argon three times. Tetrakis(triphenylphosphine)palladium (0) catalyst (51 mg, 0,044 mmol, 0.05 eq.) weighed under an argon atmosphere was added to the RBF under positive argon pressure. The flask was again evacuated and back-filled with argon three times. A 2:1 (v/v) mixture of dioxane:water (25 mL) was degassed by three cycles of freeze-pump-thaw and added to the RBF and the reaction mixture was heated to 95 °C (oil bath) for 3 days. Then the end capper, 2pinacoyl-9,9-bis((S)-3,7-dimethyloctyl)fluorene boronic ester (101 mg, 0.17 mmol, 0.2 eq.) dissolved in dioxane (degassed by three cycles of freeze-pump-thaw, 6 mL) was added to the RBF and the reaction was continued overnight. The reaction mixture was allowed to cool down to room temperature and extracted with chloroform and 1M HCl. The organic layer was washed with sat. NaHCO₃ and finally with brine. The organic layer was dried over sodium sulfate and concentrated to about 150 mL.

Purification: To the organic layer (CHCl₃, 150 mL), 28-30% aq. ammonia solution (150 mL) was added and refluxed (oil bath at 85 °C) for 3 hours and then stirred overnight at room temperature. Next day, the solution was transferred to a separating funnel and extracted with excess water. To the collected organic layer, ethylenediamine tetra-acetic acid disodium salt dihydrate (1.2 g) was addednd further stirred at room temperature overnight. After 15 hours, the organic layer was extracted with water, dried (over sodium sulfate) and evaporated to about 10-15 mL. To this concentrated solution, palladium diethyldithiocarbamic a scavenger agent, acid diethylammonium salt (25 mg) was added and stirred under dark and argon atmosphere at room temperature for 8 hours. Immediately after addition of the scavenger, the dark coloured solution turned orange. After 8 hours, the solution was poured into cold methanol (250 mL) and the yellow precipitate was collected by suction filtration and dried under vacuum at 60 °C overnight. The precipitate was then subjected to soxhlet extraction with first acetone and finally with chloroform (oil bath at 85 °C) for 24 hours each. The chloroform was concentrated to about 10 mL and poured into cold methanol (300 mL). The precipitate was collected by suction filtration and dried under vacuum at 60 °C for 24 hours to obtain yellow solid (440 mg, 82% yield).

¹H-NMR (400 MHz, CDCl₃): δ = 8.11-8.09 (m, 2H), 8.02-7.86 (m, 6 H), 2.16 (m, 4H), 1.44-1.36 (m, 2H), 1.30-0.85 (m, 19H), 0.85-0.6 ppm (m, 24H).

¹³C-NMR (100 MHz, CDCl₃): $\delta = 154.55$, 151.82, 141.14, 136.66, 133.82, 128.48, 128.08, 124.12, 120.17, 55.42, 39.42, 37.68, 36.86, 33.18, 30.94, 28.06, 24.88, 22.79, 22.69, 19.80 ppm. Both ¹H- and ¹³-C NMR spectra are in agreement with what reported in literature.²⁰

GPC (PS standard, THF); Apparent M_n : 15.36 kg mol⁻¹, M_w : 31.77 kg mol⁻¹, PDI (M_w/M_n) = 2.06

OLED fabrication and characterization: OLEDs were fabricated by spin coating in air (5000

RPM, 2000 RPM/s acceleration) mixture of PEDOT:PSS а (poly(ethylenedioxythiophene):poly(styrene sulfonate), Clevios P VP Al4083) and PFI (Nafion[®] perfluorinated resin solution, 5 wt. % in lower aliphatic alcohols and water, containing 15-20% water, Sigma-Aldrich) onto pre-cleaned, patterned indium tin oxide (ITO) substrates (15 Ω per square, Colorado Concept Coatings). PEDOT:PSS:PFI was prepared in the weight ratio 1:6:11.2. The PEDOT:PSS:PFI layer was annealed at 200°C for 20 minutes under N2 atmosphere. (Poly[(9,9-dioctylfluorenyl-2,7-diyl)-co-(4,4'-(N-(4-sec-Subsequently, a layer of TFB butylphenyl)diphenylamine)], M_p = 119 Kg/mol, M_n = 60 Kg/mol) was spin coated (2000 RPM, 2000 RPM/s acceleration) using a 8 mg/ml solution in toluene. The TFB layer was thermally annealed at 180°C for 20 minutes under N₂ atmosphere before depositing the c-PFBT layer. To c-PFBT layer was spin coated at 2000 RPM, 2000RPM/s acceleration, with concentration varied between 15 and 40 mg/mL in toluene to achieve different thicknesses. At this point the stack was further annealed at 240 °C, for 15 minutes and rapidly cooled afterwards. Finally, 10 nm of Calcium and 80 nm of Silver were thermally evaporated at a pressure of 10⁻⁶ mbar. The devices were encapsulated to limit degradation during the measurements. The OLEDs had an active area of 4.5 mm². Current-luminance-voltage curves were recorded in a setup consisting of a Keithley 2400 source meter and a calibrated silicon photodiode. The thickness of the c-PFBT layer was measured with a Bruker Dektak profilometer.

Measurement of Circularly Polarized Electro-Luminescence: electro-luminescence (EL) spectra were recorded by using an Andor Shamrock spectrometer (model SR-303i-B), equipped with a silicon CCD (model iDUS DU420A). The EL spectra were corrected for the response of the spectrometer and detector. Circular polarization was measured by placing a broad-band $\lambda/4$ waveplate (Thorlabs, AQWP05M-600) between the OLED and a linear polarizer. Measurements

were conducted using the direction of EL normal to the OLED substrate, the $\lambda/4$ waveplate and the linear polarizer. EL_L and EL_R were measured by rotating the fast axis of the $\lambda/4$ waveplate at an angle of -45° (+45°) with respect to the polarization axis of the linear polarizer, respectively. The linear polarizer was maintained in a fixed position to avoid artefacts arising from the sensitivity of the monochromator to linear polarization. A 2400 Keithley source meter was used to drive the OLEDs in constant voltage bias. A function generator (Hewlett Packard, model 8116A) coupled with a home-built high-voltage source was used for the pulsed-voltage experiments. The voltage pulses were obtained from a square wave at a repetition rate of 1 kHz, with the duration of the high-voltage state varied between 1µs and 250 µs and the 0V state maintained for the rest of the cycle. All the experiments were conducted at room temperature.

Microscopy: Atomic Force Microscopy (AFM): AFM was carried out using Asylum Research MFP-3D mounted on an anti-vibration stage. Silicone probes manufactured by NanoSensorsTM (model PPP-NCSTR-50) with a tip height of 10-15 μ m and radius of < 10 nm was used for AC tapping-mode measurement. A scan rate of 0.8 Hz and pixel size of 512×512 resolution was used. The images were subjected to first order flattening using Gwyddion (v. 2.48) software.

Polarized Optical Microscopy (POM): POM images were acquired on a Leica DM 2700 M optical microscope equipped with cross polarizers.

Circular dichroism: Circular dichroism (CD) measurements on film with thickness d < 140 nm were done on JASCO J-815 spectrometer using a scan speed of 100 nm min⁻¹, data pitch of 0.1 nm, response time of 1 second and band width of 1.71. Linear dichroism (LD) was measured on all the samples and no significant LD was observed for the samples studied. CD results on thick, d > 140 nm, films were obtained from generalized ellipsometry with a Woollam WVASE unit. The (1,4) element of the Mueller matrix in transmission geometry equals -1/2 times the

dissymmetry ratio for transmission, g_{TRANS} . Combining the Mueller matrix determination with independent measurement of the transmission, the extinctions E_{L}^{U} and E_{R}^{U} can be calculated in a straight forward manner. The (2,4) element of the Mueller matrix measured on an aligned film with alignment layer on the detector side and rubbing direction equals 1/2 times $g_{\text{TRANS}}^{\parallel}$.

Sample preparation for optical and microscopy studies: thin films were spin-coated from solution of c-PFBT with varying concentrations (from 5 mg/mL to 50 mg/mL) to obtain a range of thicknesses. All films were spin-coated from toluene, with the exception of thin films for circular dichroism (**Fig. 3a**) and aligned films (**Fig. 4c**), which were spin-coated from a solution of c-PFBT in 9:1 (v/v) chloroform:chlorobenzene. The solutions were spin-coated (2000 rpm, 60 seconds) on cleaned glass or fused silica substrates. All annealed samples were annealed for 15 minutes under nitrogen atmosphere (glove box). The film thicknesses of all films were measured using a Dektak 150 surface profiler.

Polyimide alignment layer: 2.5 cm \times 2.5 cm glass slides were cleaned by sonication for 10 minutes each with acetone and isopropyl alcohol. The glass slides were then etched in a UV-ozone photoreactor (PR-100) for 30 minutes. Polyimide (AL 1051) was spin-coated on etched glass-slides (5000 rpm, 40 seconds, 500 rpm acceleration) and then annealed at 180 °C for 90 minutes. The polyimide facing side was rubbed on a velvet cloth to induce planar alignment.

Circular polarization of photo-luminescence: Measurements were done using a home-built setup employing a photo-elastic modulator and a 16-channel photomultiplier array involving a photon counting detection scheme. 365 nm excitation light was selected from a Hg lamp using appropriate interference and bandpass filters. The excitation light was depolarized by passing it through a bundle of optical fibres. The direction of the excitation was normal to the surface of the film and in line with the direction of emission collection.

Ellipsometry: Generalized ellipsometry measurements were carried out with the Woollam WVASE ellipsometer using the general Mueller matrix measurement protocol.

Corresponding Author

* Daniele Di Nuzzo (dd467@cam.ac.uk)

Acknowledgements

D.D.N. and R.H.F. acknowledge financial support from the Engineering and Physical Sciences Research Council of the UK (EPSRC). C.K. and E.W.M. acknowledge financial support from the Dutch Ministry of Education, Culture and Science (Gravity program 024.001.035). C.K. thanks financial support from Marie Skłodowska-Curie (704830) postdoctoral fellowship.

Supporting Information Available: Current-Luminance-Voltage characteristics, g_{EL} as function of operation mode, experimental values of δ^2 . This material is available free of charge *via* the Internet at http://pubs.acs.org.

References

(1) Hövel, S.; Gerhardt, N. C.; Hofmann, M. R.; Lo, F.-Y.; Reuter, D.; Wieck, A. D.; Schuster, E.; Keune, W.; Wende, H.; Petracic, O.; *et al.* Electrical Detection of Photoinduced Spins Both at Room Temperature and in Remanence. *Appl. Phys. Lett.* **2008**, *92*, 242102.

(2) Farshchi, R.; Ramsteiner, M.; Herfort, J.; Tahraoui, A.; Grahn, H. T. Optical Communication of Spin Information between Light Emitting Diodes. *Appl. Phys. Lett.* **2011**, *98*, 162508.

(3) Wang, C. S.; Fei, H. S.; Qiu, Y.; Yang, Y. Q.; Wei, Z. Q. Photoinduced Birefringence and Reversible Optical Storage in Liquid-Crystalline Azobenzene Side-Chain Polymers. *Appl. Phys. Lett.* **1999**, *74*, 19–21.

(4) Liu, C.; Yang, D.; Jin, Q.; Zhang, L.; Liu, M. A Chiroptical Logic Circuit Based on Self-Assembled Soft Materials Containing Amphiphilic Spiropyran. *Adv. Mater.* **2016**, *28*, 1644–1649.

Novikova, T.; Pierangelo, A.; Manhas, S.; Benali, A.; Validire, P.; Gayet, B.; De Martino,
A. The Origins of Polarimetric Image Contrast between Healthy and Cancerous Human Colon
Tissue. *Appl. Phys. Lett.* 2013, *102*, 241103.

(6) Kunnen, B.; Macdonald, C.; Doronin, A.; Jacques, S.; Eccles, M.; Meglinski, I. Application of Circularly Polarized Light for Non-Invasive Diagnosis of Cancerous Tissues and Turbid Tissue-like Scattering Media. *J. Biophotonics* **2015**, *8*, 317–323.

(7) McNichols, R. J.; Cote, G. L. Optical Glucose Sensing in Biological Fluids: An Overview. J. Biomed. Opt. 2000, 5, 5–16.

(8) Lee, D.-M.; Song, J.-W.; Lee, Y.-J.; Yu, C.-J.; Kim, J.-H. Control of Circularly Polarized Electroluminescence in Induced Twist Structure of Conjugate Polymer. *Adv. Mater.* **2017**, *29*, 1700907.

(9) Zinna, F.; Pasini, M.; Galeotti, F.; Botta, C.; Di Bari, L.; Giovanella, U. Design of Lanthanide-Based OLEDs with Remarkable Circularly Polarized Electroluminescence. *Adv. Funct. Mater.* **2017**, *27*, 1603719.

30

(10) Brandt, J. R.; Wang, X.; Yang, Y.; Campbell, A. J.; Fuchter, M. J. Circularly Polarized Phosphorescent Electroluminescence with a High Dissymmetry Factor from PHOLEDs Based on a Platinahelicene. *J. Am. Chem. Soc.* **2016**, *138*, 9743–9746.

(11) Li, T.-Y.; Jing, Y.-M.; Liu, X.; Zhao, Y.; Shi, L.; Tang, Z.; Zheng, Y.-X.; Zuo, J.-L. Circularly Polarised Phosphorescent Photoluminescence and Electroluminescence of Iridium Complexes. *Sci. Rep.* **2015**, *5*, 14912.

(12) Han, J.; Guo, S.; Wang, J.; Wei, L.; Zhuang, Y.; Liu, S.; Zhao, Q.; Zhang, X.; Huang, W.
 Circularly Polarized Phosphorescent Electroluminescence from Chiral Cationic Iridium(III)
 Isocyanide Complexes. *Adv. Opt. Mater.* 2017, *5*, 1700359.

(13) Peeters, E.; Christiaans, M. P. T.; Janssen, R. A. J.; Schoo, H. F. M.; Dekkers, H.; Meijer,
E. W. Circularly Polarized Electroluminescence from a Polymer Light-Emitting Diode. *J. Am. Chem. Soc.* 1997, *119*, 9909–9910.

Oda, M.; Nothofer, H. G.; Lieser, G.; Scherf, U.; Meskers, S. C. J.; Neher, D. Circularly
 Polarized Electroluminescence from Liquid-Crystalline Chiral Polyfluorenes. *Adv. Mater.* 2000, *12*, 362–365.

(15) Geng, Y. H.; Trajkovska, A.; Culligan, S. W.; Ou, J. J.; Chen, H. M. P.; Katsis, D.; Chen,
S. H. Origin of Strong Chiroptical Activities in Films of Nonafluorenes with a Varying Extent of
Pendant Chirality. *J. Am. Chem. Soc.* 2003, *125*, 14032–14038.

(16) Yang, Y.; da Costa, R. C.; Smilgies, D.-M.; Campbell, A. J.; Fuchter, M. J. Induction of Circularly Polarized Electroluminescence from an Achiral Light-Emitting Polymer via a Chiral Small-Molecule Dopant. *Adv. Mater.* **2013**, *25*, 2624–2628.

(17) Blok, P.; Dekkers, H. Discrimination Between 3-Pi-Pi-Star and 3n-Pi-Star States in Organic Molecules by Circular-Polarization of Phosphorescence. *Chem. Phys. Lett.* **1989**, *161*, 188–194.

(18) Lunkley, J. L.; Shirotani, D.; Yamanari, K.; Kaizaki, S.; Muller, G. Extraordinary Circularly Polarized Luminescence Activity Exhibited by Cesium Tetrakis(3-Heptafluoro-Butylryl-(+)-Camphorato) Eu(III) Complexes in EtOH and CHC13 Solutions. *J. Am. Chem. Soc.* 2008, *130*, 13814–13815.

(19) Geng, Y. H.; Trajkovska, A.; Katsis, D.; Ou, J. J.; Culligan, S. W.; Chen, S. H. Synthesis, Characterization, and Optical Properties of Monodisperse Chiral Oligofluorenes. *J. Am. Chem. Soc.* **2002**, *124*, 8337–8347.

(20) Abbel, R.; Schenning, A. P. H. J.; Meijer, E. W. Molecular Weight Optimum in the Mesoscopic Order of Chiral Fluorene (Co)Polymer Films. *Macromolecules* 2008, *41*, 7497–7504.

(21) Lakhwani, G.; Meskers, S. C. J. Insights from Chiral Polyfluorene on the Unification of Molecular Exciton and Cholesteric Liquid Crystal Theories for Chiroptical Phenomena. *J. Phys. Chem. A* **2012**, *116*, 1121–1128.

(22) Lee, T.-W.; Chung, Y.; Kwon, O.; Park, J.-J. Self-Organized Gradient Hole Injection to Improve the Performance of Polymer Electroluminescent Devices. *Adv. Funct. Mater.* **2007**, *17*, 390–396.

(23) Kim, J. S.; Friend, R. H.; Grizzi, I.; Burroughes, J. H. Spin-Cast Thin Semiconducting Polymer Interlayer for Improving Device Efficiency of Polymer Light-Emitting Diodes. *Appl. Phys. Lett.* **2005**, *87*, 023506.

32

(24) Lakhwani, G.; Meskers, S. C. J.; Janssen, R. A. J. Circular Differential Scattering of Light in Films of Chiral Polyfluorene. *J. Phys. Chem. B* **2007**, *111*, 5124–5131.

(25) Dmitrienko, V.; Belyakov, V. Contribution to the Theory of the Optical Properties of Imperfect Cholesteric Liquid Crystals. *Sov. Phys. JETP* **1977**, *46*, 362–356.

(26) Kabra, D.; Lu, L. P.; Song, M. H.; Snaith, H. J.; Friend, R. H. Efficient Single-Layer Polymer Light-Emitting Diodes. *Adv. Mater.* **2010**, *22*, 3194–3198.

(27) Bracher, C.; Yi, H.; Scarratt, N. W.; Masters, R.; Pearson, A. J.; Rodenburg, C.; Iraqi, A.; Lidzey, D. G. The Effect of Residual Palladium Catalyst on the Performance and Stability of PCDTBT:PC70BM Organic Solar Cells. *Org. Electron.* **2015**, *27*, 266–273.

(28) Patel, D. G.; Graham, K. R.; Reynolds, J. R. A Diels-Alder Crosslinkable Host Polymer for Improved PLED Performance: The Impact on Solution Processed Doped Device and Multilayer Device Performance. *J. Mater. Chem.* **2012**, *22*, 3004–3014.